

BC857BW-QX Datasheet



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DiGi Electronics Part Number BC857BW-QX-DG

Manufacturer Nexperia USA Inc.

Manufacturer Product Number BC857BW-QX

Description TRANS NPN 45V 0.1A SOT323

Detailed Description Bipolar (BJT) Transistor NPN 45 V 100 mA 100MHz 2

00 mW Surface Mount SOT-323



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Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
BC857BW-QX	Nexperia USA Inc.
Series:	Product Status:
BC847xW-Q	Active
Transistor Type:	Current - Collector (Ic) (Max):
NPN	100 mA
Voltage - Collector Emitter Breakdown (Max):	Vce Saturation (Max) @ lb, lc:
45 V	400mV @ 5mA, 100mA
Current - Collector Cutoff (Max):	DC Current Gain (hFE) (Min) @ Ic, Vce:
15nA (ICBO)	200 @ 2mA, 5V
Power - Max:	Frequency - Transition:
200 mW	100MHz
Operating Temperature:	Grade:
150°C (TJ)	Automotive
Qualification:	Mounting Type:
AEC-Q101	Surface Mount
Package / Case:	Supplier Device Package:
SC-70, SOT-323	SOT-323
Base Product Number:	
BC857	

Environmental & Export classification

8541.21.0075

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	



65 V, 100 mA PNP general-purpose transistors

Rev. 2 — 10 July 2023

Product data sheet

1. General description

PNP general-purpose transistors in a very small SOT323 (SC-70), Surface-Mounted Device (SMD) plastic package.

Table 1. Product overview

Type number	Package		NPN complement
	Nexperia	JEDEC	
BC856W-Q	SOT323	SC-70	BC846W-Q
BC856AW-Q			BC846AW-Q
BC856BW-Q			BC846BW-Q
BC857W-Q			BC847W-Q
BC857AW-Q			BC847AW-Q
BC857BW-Q			BC847BW-Q
BC857CW-Q			BC847CW-Q
BC858W-Q	1		BC848W-Q

2. Features and benefits

- Low current (max. 100 mA)
- Low voltage (max. 65 V)
- Qualified according to AEC-Q101 and recommended for use in automotive applications

3. Applications

· General-purpose switching and amplification



4. Quick reference data

Table 2. Quick reference data

 T_{amb} = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{CEO}	collector-emitter voltage	open base				
	BC856W-Q		-	-	-65	V
	BC857W-Q		-	-	-45	V
	BC858W-Q		-	-	-30	V
I _C	collector current		-	-	-100	mA
I _{CM}	peak collector current		-	-	-200	mA
h _{FE}	DC current gain					
	BC856W-Q		125	-	475	
	BC857W-Q; BC858W-Q	V = 5 V(1 = 2 m A	125	-	800	
	BC856AW-Q; BC857AW-Q	$V_{CE} = 5 \text{ V}; I_{C} = 2 \text{ mA}$	125	-	250	
	BC856BW-Q; BC857BW-Q		220	-	475	
	BC857CW-Q		420	-	800	

5. Pinning information

Table 3. Pinning information

Pin	Symbol	Descrition	Simlified outline	Graphic symbol
1	В	base] 3	C
2	Е	emitter		В—
3	С	collector		, h
				E sym132
				3,52

6. Ordering information

Table 4. Ordering information

Type number	Package						
	Name	Description	Version				
BC856W-Q	SC-70	plastic surface-mounted package; 3 leads	SOT323				
BC856AW-Q							
BC856BW-Q							
BC857W-Q							
BC857AW-Q							
BC857BW-Q							
BC857CW-Q							
BC858W-Q							

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7. Marking

Table 5. Marking codes

Type number		Marking code
BC856W-Q	[1]	3D%
BC856AW-Q	[1]	3A%
BC856BW-Q	[1]	3B%
BC857W-Q	[1]	3H%
BC857AW-Q	[1]	3E%
BC857BW-Q	[1]	3F%
BC857CW-Q	[1]	3G%
BC858W-Q	[1]	3M%

^{[1] % =} placeholder for manufacturing site code

8. Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{CBO}	collector-base voltage	open emitter				
	BC856W-Q			-	-80	V
	BC857W-Q			-	-50	V
	BC858W-Q			-	-30	V
V _{CEO}	collector-emitter voltage	open base				
	BC856W-Q			-	-65	V
	BC857W-Q			-	-45	V
	BC858W-Q			-	-30	V
V _{EBO}	emitter-base voltage	open collector		-	-5	V
I _C	collector current			-	-100	mA
I _{CM}	peak collector current			-	-200	mA
I _{BM}	peak base current			-	-200	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	200	mW
Tj	junction temperature			-	150	°C
T _{amb}	ambient temperature			-65	150	°C
T _{stg}	storage temperature			-65	150	°C

^[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided, 35 µm copper, tin-plated and standard footprint.

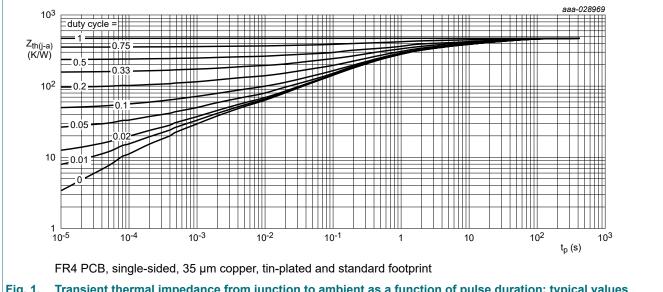
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9. Thermal characteristics

Table 7. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
· -ui(y-a)	thermal resistance from junction to ambient	in free air	[1]	-	-	625	K/W

[1] Device mounted on an FR4 PCB; single-sided; 35 µm copper; tin-plated and standard footprint.



Transient thermal impedance from junction to ambient as a function of pulse duration; typical values Fig. 1.

10. Characteristics

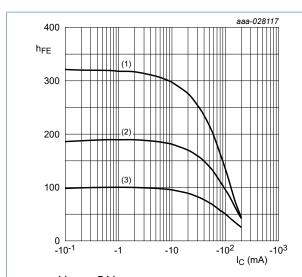
Table 8. Characteristics

 T_{amb} = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{(BR)CBO}	collector-base breakdown	voltage					
	BC856W-Q			-80	-	-	V
BC857W-Q		I _C = -100 μA; I _E = 0 A		-50	-	-	V
	BC858W-Q			-30	-	-	V
V _{(BR)CEO}	collector-emitter breakdow	vn voltage					
	BC856W-Q			-65	-	-	V
BC857W-Q		$I_{C} = -2 \text{ mA}; I_{B} = 0 \text{ A}$		-45	-	-	V
	BC858W-Q			-30	-	-	V
V _{(BR)EBO}	emitter-base breakdown voltage	I _C = 0 A; I _E = -100 μA		-5	-	-	V
СВО	collector-base	V _{CB} = -30 V; I _E = 0 A		-	-1	-15	nA
	cut-off current	$V_{CB} = -30 \text{ V}; I_E = 0 \text{ A}; T_j = 150 \text{ °C}$		-	-	-4	μA
I _{ЕВО}	emitter-base cut-off current	$V_{EB} = -5 \text{ V}; I_C = 0 \text{ A}$		-	-	-100	nA
1 _{FE}	DC current gain						
BC856W-Q			125	-	475		
	BC857W-Q BC858W-Q BC856AW-Q BC857AW-Q	V _{CE} = -5 V; I _C = -2 mA		125	-	800	
				125	-	250	
	BC857BW-Q BC858BW-Q			220	-	475	
	BC857CW-Q			420	-	800	
V _{CEsat}	collector-emitter	I _C = -10 mA; I _B = -0.5 mA		-	-75	-300	mV
	saturation voltage	I _C = -100 mA; I _B = -5 mA	[1]	-	-250	-600	mV
V _{BEsat}	base-emitter saturation	I _C = -10 mA; I _B = -0.5 mA	[1]	-	-700	-	mV
	voltage	I _C = -100 mA; I _B = -5 mA	[1]	-	-850	-	mV
V _{BE}	base-emitter voltage	V _{CE} = -5 V; I _C = -2 mA		-600	-650	-750	mV
		V _{CE} = -5 V; I _C = -10 mA		-	-	-820	mV
C _c	collector capacitance	V _{CB} = -10 V; I _E = i _e = 0 A; f = 1 MHz		-	3	-	pF
C _e	collector capacitance	$V_{EB} = -5 \text{ V}; I_C = i_c = 0 \text{ A}; f = 1 \text{ MHz}$		-	12	-	pF
T	transition frequency	V _{CE} = -5 V; I _C = -10 mA; f = 100 MHz		100	-	-	MHz
NF	noise figure	I_C = -200 μA; V_{CE} = -5 V; R_S = 2 kΩ; f = 1 kHz; B = 200Hz		-	2	10	dB

[1] pulsed; $t_p \le 300 \ \mu s; \ \delta \le 0.02$

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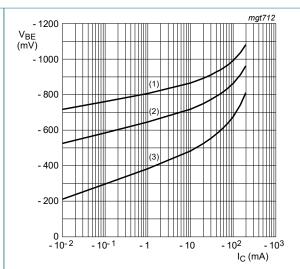
$$V_{CE}$$
 = -5 V

(1)
$$T_{amb} = 150 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -55 \, ^{\circ}C$$





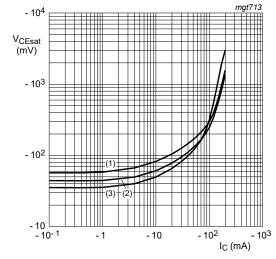
$$V_{CE} = -5 V$$

(1)
$$T_{amb} = -55 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = 150 \, ^{\circ}C$$

Fig. 3. BC856AW-Q; BC857AW-Q: Base-emitter voltage as a function of collector current; typical values



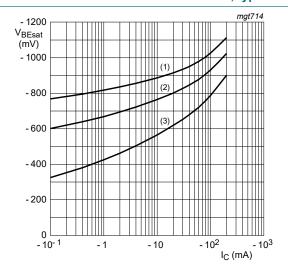
$$I_{\rm C}/I_{\rm B} = 20$$

(1)
$$T_{amb} = 150 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -55 \, ^{\circ}C$$

Fig. 4. BC856AW-Q; BC857AW-Q: Collector-emitter saturation voltage as a function of collector current; typical values



$$I_{\rm C}/I_{\rm B} = 20$$

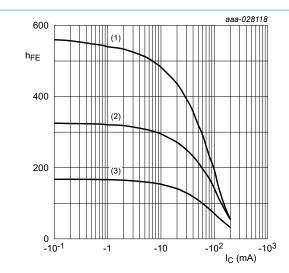
(1)
$$T_{amb} = -55$$
 °C

(2)
$$T_{amb}$$
 = 25 °C

(3)
$$T_{amb} = 150 \, ^{\circ}C$$

Fig. 5. BC856AW-Q; BC857AW-Q: Base-emitter saturation voltage as a function of collector current; typical values

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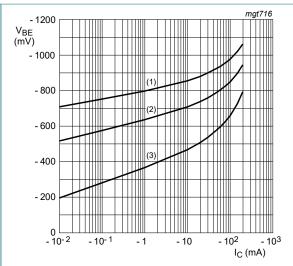
$$V_{CE} = -5 V$$

(1)
$$T_{amb} = 150 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -55 \, ^{\circ}C$$

Fig. 6. BC856BW-Q; BC857BW-Q; BC858BW-Q: DC current gain as a function of collector current; typical values

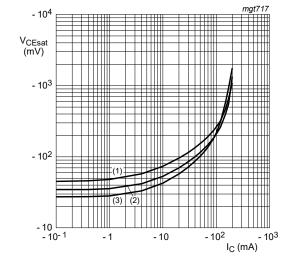


$$V_{CE} = -5 V$$

(1)
$$T_{amb} = -55 \, ^{\circ}C$$

(3)
$$T_{amb} = 150 \, ^{\circ}C$$

Fig. 7. BC856BW-Q; BC857BW-Q; BC858BW-Q:
Base-emitter voltage as a function of collector current; typical values



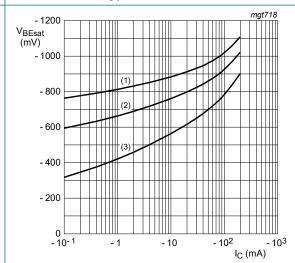
$$I_{\rm C}/I_{\rm B} = 20$$

(1)
$$T_{amb} = 150 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -55 \, ^{\circ}C$$

Fig. 8. BC856BW-Q; BC857BW-Q; BC858BW-Q: Collector-emitter saturation voltage as a function of collector current; typical values



$$I_{\rm C}/I_{\rm B} = 20$$

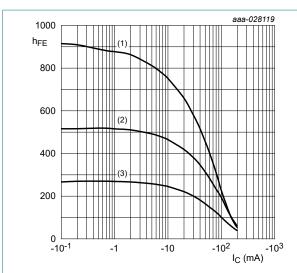
(1)
$$T_{amb} = -55 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = 150 \, ^{\circ}C$$

Fig. 9. BC856BW-Q; BC857BW-Q; BC858BW-Q: Baseemitter saturation voltage as a function of collector current; typical values

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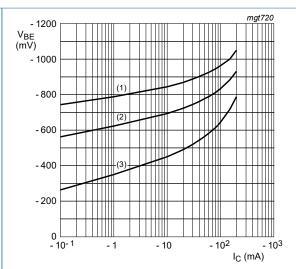
$$V_{CE} = -5 V$$

(1)
$$T_{amb} = 150 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -55 \, ^{\circ}C$$

Fig. 10. BC857CW-Q: DC current gain as a function of collector current; typical values



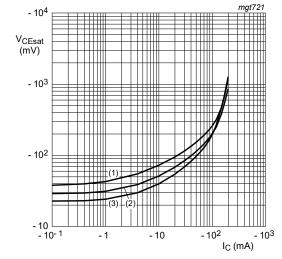
$$V_{CE}$$
 = -5 V

(1)
$$T_{amb} = -55 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = 150 \, ^{\circ}C$$

Fig. 11. BC857CW-Q: Base-emitter voltage as a function of collector current; typical values



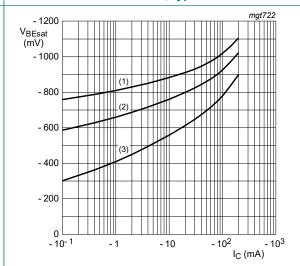
$$I_{\rm C}/I_{\rm B} = 20$$

(1)
$$T_{amb} = 150 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

$$(3) T_{amb} = -55 °C$$

Fig. 12. BC857CW-Q: Collector-emitter saturation voltage as a function of collector current; typical values



$$I_{\rm C}/I_{\rm B} = 20$$

(1)
$$T_{amb} = -55$$
 °C

(2)
$$T_{amb}$$
 = 25 °C

Fig. 13. BC857CW-Q: Base-emitter saturation voltage as a function of collector current; typical values

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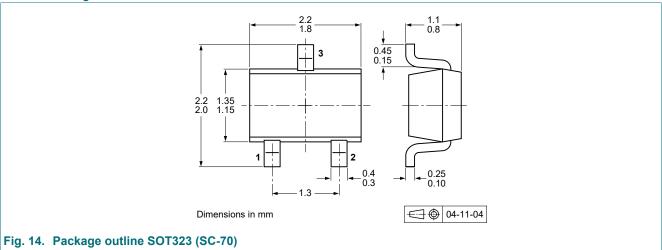
11. Test information

11.1. Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

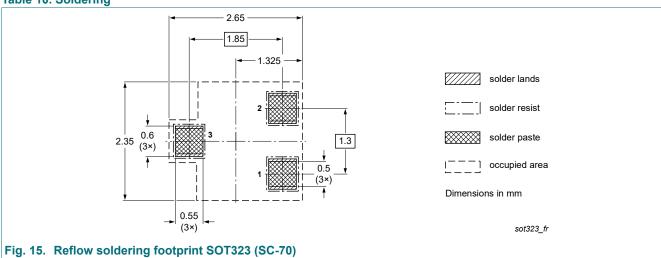
12. Package outline

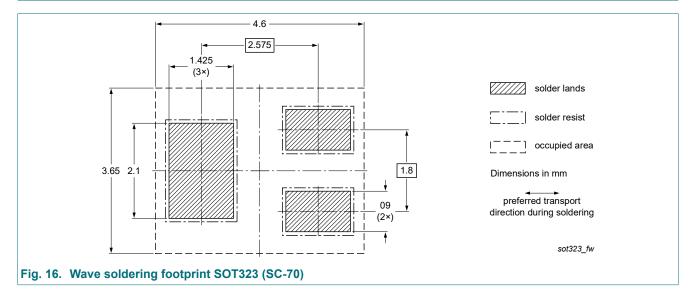




13. Soldering







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14. Revision history

Table 11. Revision history

Table 11. Revision mistory							
Document ID	Release date	Data sheet status	Change notice	Supersedes			
BC856W-Q_BC857W- Q_BC858W-Q v.2	20230710	Product data sheet	-	-			
Modifications:	Quick reference	Quick reference data: typos corrected					
BC856W-Q_BC857W- Q_BC858W-Q v.1	20211203	Product data sheet	-	-			

65 V, 100 mA PNP general-purpose transistors

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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Nexperia

BC856W-Q; BC857W-Q; BC858W-Q

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	General description

For more information, please visit: http://www.nexperia.com For sales office addresses, please send an email to: salesaddresses@nexperia.com Date of release: 10 July 2023

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